

# Very Low Forward Voltage Trench-based Schottky Rectifier

# NRVTS2H60ESF, NRVTSM260EV2

#### **Features**

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Mechanical Characteristics:**

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 11.7 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds
- MSL 1

#### **Typical Applications**

 Switching Power Supplies including Compact Adapters and Flat Panel Display

1

- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

# TRENCH SCHOTTKY RECTIFIER 2.0 AMPERES 60 VOLTS

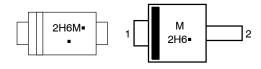




SOD-123FL CASE 498

POWERMITE CASE 457

#### **MARKING DIAGRAMs**



2H6 = Specific Device Code
M = Date Code
Device Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NRVTS2H60ESFT1G	SOD-123FL (Pb-Free)	3,000 / Tape & Reel
NRVTS2H60ESFT3G	SOD-123FL (Pb-Free)	10,000 / Tape & Reel
NRVTSM260EV2T1G	Powermite (Pb-Free)	3,000 / Tape & Reel
NRVTSM260EV2T3G	Powermite (Pb-Free)	12,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## NRVTS2H60ESF, NRVTSM260EV2

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current (T <sub>L</sub> = 125°C)	Io	2.0	Α
Peak Repetitive Forward Current (Square Wave, 20 kHz, T <sub>L</sub> = 139°C)	I <sub>FRM</sub>	4.0	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	50	Α
Storage and Operating Junction Temperature Range (Note 1)	T <sub>stg</sub> , T <sub>J</sub>	-65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
SOD-123FL			
Thermal Resistance, Junction-to-Lead (Note 2)	$\Psi_{\sf JCL}$	24.4	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	85	°C/W
Thermal Resistance, Junction-to-Ambient (Note 3)		330	°C/W
POWERMITE			
Thermal Resistance, Junction-to-Lead (Note 2)	$\Psi_{JCL}$	8.6	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	80	°C/W
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	237	°C/W

#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Value	Unit
	V <sub>F</sub>	0.55 0.65 0.47 0.58	V
Maximum Instantaneous Reverse Current (Note 4) (Rated dc Voltage, $T_J = 25^{\circ}C$ ) (Rated dc Voltage, $T_J = 125^{\circ}C$ )	I <sub>R</sub>	12 3	μA mA

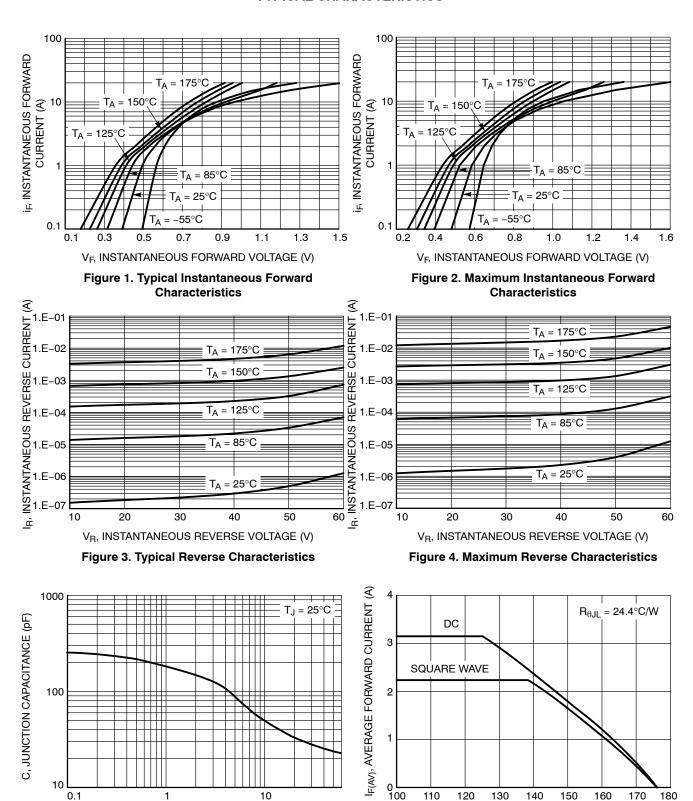
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 2. Mounted with 700 mm<sup>2</sup> copper pad size (Approximately 1 in<sup>2</sup>) 1 oz FR4 Board.
- 3. Mounted with pad size approximately 20 mm<sup>2</sup> copper, 1 oz FR4 Board.
- 4. Pulse Test: Pulse Width  $\leq$  380  $\mu$ s, Duty Cycle  $\leq$  2.0%.

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## NRVTS2H60ESF, NRVTSM260EV2

#### **TYPICAL CHARACTERISTICS**



T<sub>C</sub>, CASE TEMPERATURE (°C)

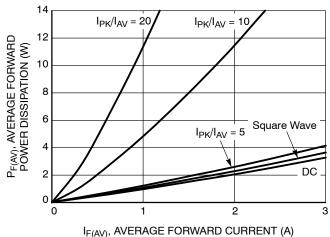
Figure 6. Current Derating

V<sub>R</sub>, REVERSE VOLTAGE (V)

Figure 5. Typical Junction Capacitance

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#### **TYPICAL CHARACTERISTICS**



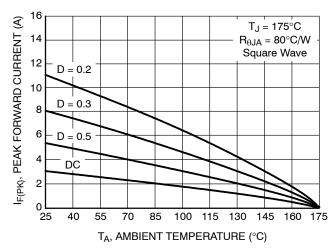
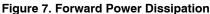


Figure 8. Forward Current Derating of Ambient Temperature



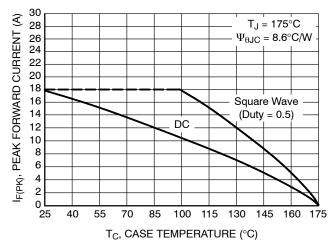


Figure 9. Forward Current Derating of Case Temperature

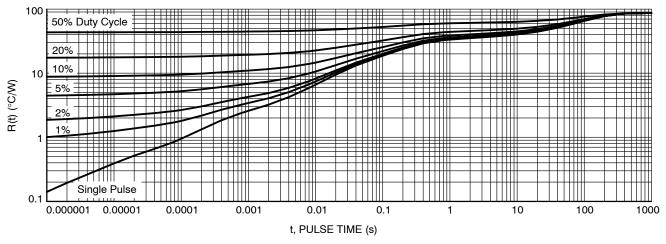
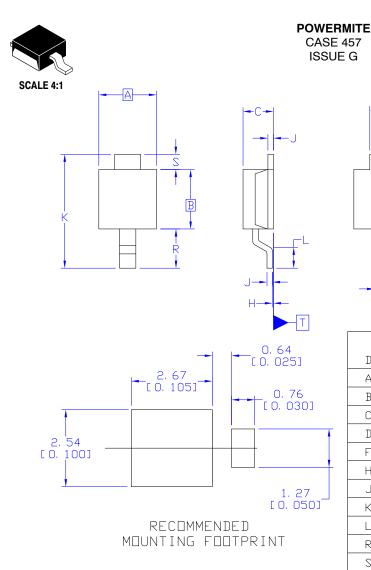


Figure 10. Thermal Characteristics



**DATE 12 JAN 2022** 



**GENERIC** 

**MARKING DIAGRAMS\*** 

M

XXX.

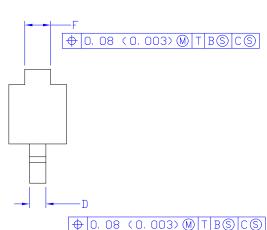
STYLE 3

M

XXX.

STYLE 2

2



	MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.
Α	1. 75	2, 05	0, 069	0. 081
В	1. 75	2, 18	0, 069	0, 086
С	0, 85	1. 15	0. 033	0. 045
D	0. 40	0, 69	0, 016	0. 027
F	0. 70	1, 00	0, 028	0, 039
Н	-0, 05	0, 10	-0, 002	0, 004
J	0, 10	0, 25	0, 004	0.010
K	3, 60	3, 90	0.142	0.154
L	0, 50	0, 80	0, 020	0, 031
R	1. 20	1, 50	0. 047	0. 059
S	0, 50	REF	0, 019	REF

# NOTES:

STYLE 1:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION & APPLIES TO PLATED TERMINAL 3. AND IS MEASURED BETWEEN O. 15 AND O. 30mm FROM THE TERMINAL TIP.

	STYLE 1	l:
2		CATHODE ANODE
		*This info
XXX = Specific Device C	Code	Pb-Free
M = Date Code		or may r

= Pb-Free Package

STYLE 2: PIN 1. ANODE OR CATHODE 2. CATHODE OR ANODE (BI-DIRECTIONAL)

STYLE 3: PIN 1. ANODE 2. CATHODE

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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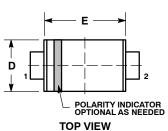
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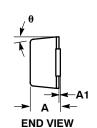
STYLE 1

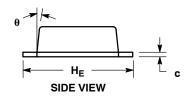


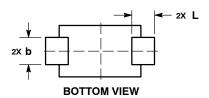
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**DATE 10 MAY 2013** 

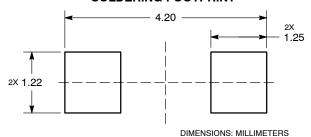








# RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- ES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH.
  DIMENSIONS D AND J ARE TO BE MEASURED ON FLAT SECTION
  OF THE LEAD: BETWEEN 0.10 AND 0.25 MM FROM THE LEAD TIP.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	0.95	0.98	0.035	0.037	0.039
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.70	0.90	1.10	0.028	0.035	0.043
С	0.10	0.15	0.20	0.004	0.006	0.008
D	1.50	1.65	1.80	0.059	0.065	0.071
E	2.50	2.70	2.90	0.098	0.106	0.114
L	0.55	0.75	0.95	0.022	0.030	0.037
HE	3.40	3.60	3.80	0.134	0.142	0.150
θ	0°	-	8°	0°	-	8°

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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